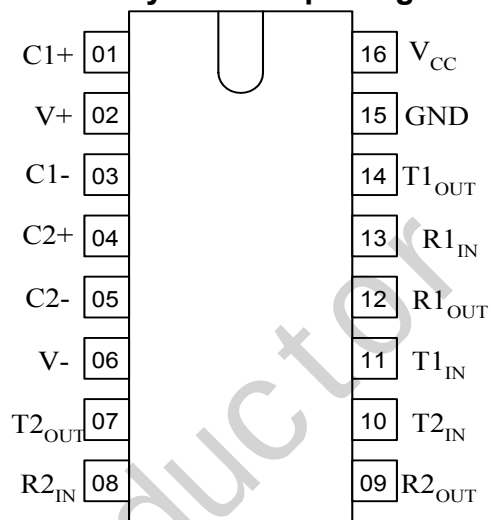


IC SP232EEN is purposed for application in high-performance information processing systems and control devices of wide application. Input voltage levels are compatible with standard CMOS levels.

- Output voltage levels are compatible with input levels of C-MOS, N-MOS and TTL integrated circuits.
- Supply voltage range from 2.0 to 6.0 V.
- Low input current: 1.0 mA; 0.1 mA at $T = 25^{\circ}\text{C}$.
- Output current 24 mA.
- Latching current not less than 450 mA at $T = 25^{\circ}\text{C}$
- Tolerable value of static potential not less than 2000V

Pin symbols in package



Truth table

Inputs	Outputs
R_{IN}, T_{IN}	R_{OVT}, T_{OVT}
H	L
L	H
Note - H – voltage high level; L – low voltage level	

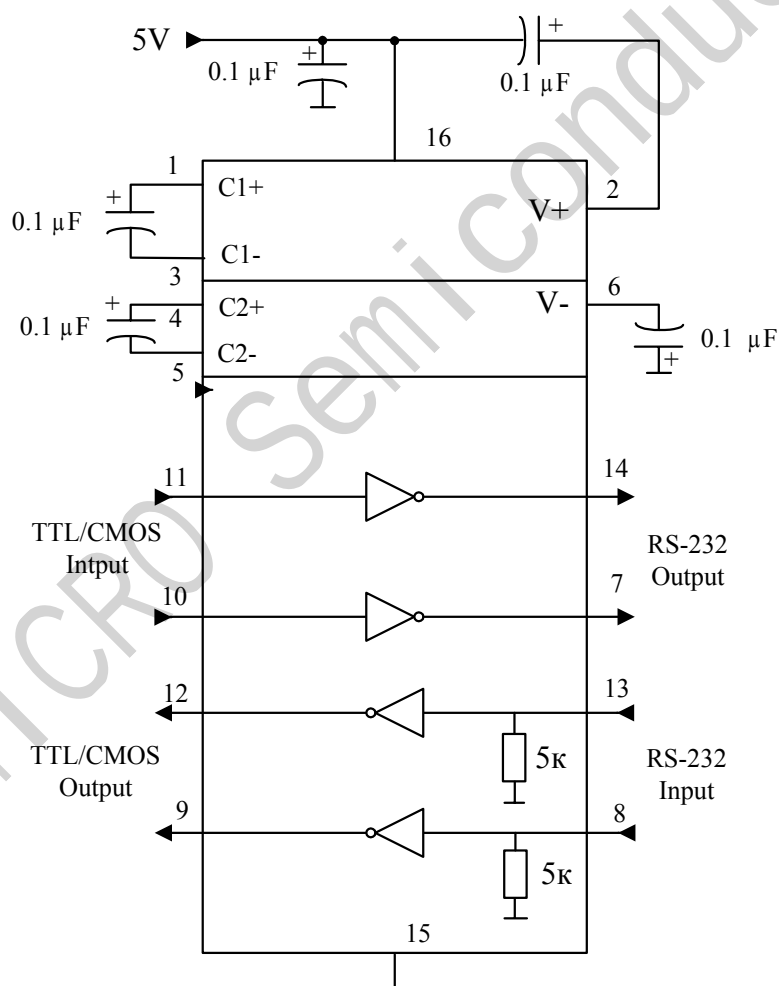
Table of pin description

Pin No.	Symbol	Pin name
01	C1+	Output of external capacitance of positive voltage multiplier unit
02	V+	Output of positive voltage of multiplier unit
03	C1-	Output of external capacitance of positive voltage multiplier unit
04	C2+	Output of external capacitance of negative voltage multiplier unit
05	C2-	Output of external capacitance of negative voltage multiplier unit
06	V-	Output of negative voltage of multiplier unit
07	T2 _{OUT}	Output of transmitter data (levels RS – 232)
08	R2 _{IN}	Input of receiver data (levels RS – 232)
09	R2 _{OUT}	Output of receiver data (levels TTL/KMOS)
10	T2 _{IN}	Input of transmitter data (levels TTL/KMOS)
11	T1 _{IN}	Input of transmitter data (levels TTL/KMOS)
12	R1 _{OUT}	Output of receiver data (levels TTL/KMOS)
13	R1 _{IN}	Input of receiver data (levels RS – 232)
14	T1 _{OUT}	Output of transmitter data (levels RS – 232)
15	GND	Common output
16	V _{CC}	Supply output of voltage source

Maximum conditions

Symbol	Parameter	Rate		Unit
		min	max	
V _{CC}	Supply voltage	-0.3	6.0	V
V+	Transmitter high output voltage	V _{CC} - 0.3	14	
V-	Transmitter low output voltage	-0.3	-14	
V _{TIN}	Transmitter input voltage	-0.3	V+ + 0.3	
V _{RIN}	Receiver input voltage	-30	30	mW
P _D	Dissipated power	-		
	DIP – package		842	
	SO - package		762	
I _{SC}	Output current of transmitter short circuit	-	Continuously	mA
Ta	Ambient temperature	-60	150	°C

Symbol	Parameter	Rate		Unit
		min	max	
V _{CC}	Supply voltage	4.5	5.5	V
V+	Transmitter output high voltage	5.0	-	
V-	Transmitter output low voltage	-5.0	-	
V _{TIN}	Transmitter input voltage	0	V _{CC}	
V _{RIN}	Receiver input voltage	-30	30	
I _{SC}	Transmitter short circuit output current	-	±60	mA
Ta	Ambient temperature	-40	85	°C



Symbol	Parameter	Test conditions	Rate				Unit
			25°C		от -40 °C до 85 °C		
			min	max	min	max	
I _{CC}	Consumption current static	V _{CC} = 5.5 V V _{IL} = 0 V	-	10.0	-	14.0 *	mA
Receiver electrical parameters							
V _h	Hysteresis voltage	V _{CC} = 5.0 V	0.2	0.9	0.2	1.0	V
V _{On}	On (operation) voltage	V _O ≤ 0.1 V I _{OL} ≤ 20 mA	-	2.4	-	2.3	
V _{off}	Off (dropout) voltage	V _O ≥ V _{CC} - 0.1 V I _{OH} ≤ -20 mA	0.8	-	0.9	-	
V _{OL}	Output low voltage	I _{OL} = 3.2 mA V _{CC} = 4.5 V V _{IH} = 2.4 V	-	0.3	-	0.4	
V _{OH}	Output high voltage	I _{OH} = -1.0 mA V _{CC} = 4.5 V V _{IL} = 0.8 V	3.6	-	3.5	-	
R _I	Input resistance	V _{CC} = 5.0 V	3.0	7.0	3.0	7.0	kOhm
Transmitter electrical parameters							
V _{OL}	Output low voltage	V _{CC} = 4.5 V V _{IH} = 2.0 V R _L = 3.0 kOhm	-	-5.2	-	-5.0	V
V _{OH}	Output high voltage	V _{CC} = 4.5 V V _{IL} = 0.8 V R _L = 3.0 kOhm	5.2	-	5.0	-	
I _{IL}	Input low current	V _{CC} = 5.5 V V _{IL} = 0 V	-	-1.0	-	-10.0	mA
I _{IH}	Input high current	V _{CC} = 5.5 V V _{IH} = V _{CC}		1.0		10.0	
SR	Speed of output front change	V _{CC} = 5.0 V C _L = 50 - 1000 pF R _L = 3.0 - 7.0 kOhm	3.0	30	2.7	27	V/mks
R _O	Output resistance	V _{CC} = V ₊ = V ₋ = 0 V V _O = ± 2 V	350	-	300	-	Ohm
I _{sc}	Short circuit output current	V _{CC} = 5.5 V V _O = 0 V V _I = V _{CC} V _I = 0 V		-50 50		-60 60	mA
ST	Speed of information transmission	V _{CC} = 4.5 V C _L = 1000 pF R _L = 3.0 kOhm t _w = 7mks (for extreme -t _w = 8mks)	140	-	120	-	

Symbol	Parameter	Test conditions	Rate				Unit
			25 °C		from -40 °C to 85 °C		
			min	max	min	max	
t_{PHLR} (t_{PLHR})	Signal propagation delay time when switching on (off)	$V_{CC} = 4.5\text{ V}$ $C_L = 150\text{ pF}$ $V_{IL} = 0\text{ V}$ $V_{IH} = 3.0\text{ V}$ $t_{LH} = t_{HL} \leq 10\text{ ns}$	-	9.7	-	10	mks
t_{PHLT} (t_{PLHT})	Signal propagation delay time when switching on (off)	$V_{CC} = 4.5\text{ V}$ $C_L = 2500\text{ pF}$ $V_{IL} = 0\text{ V}$ $V_{IH} = 3.0\text{ V}$ $R_L = 3\text{ kOhm}$ $t_{LH} = t_{HL} \leq 10\text{ ns}$		5.0*		6.0*	

Capacitance

Symbol	Parameter	V_{CC} , V	Rate	Unit
C_{IN}	Input capacitance	5.0	9.0	pF
C_{PD}	Dynamic capacitance		90	

Timing diagram when measuring IC dynamic parameters

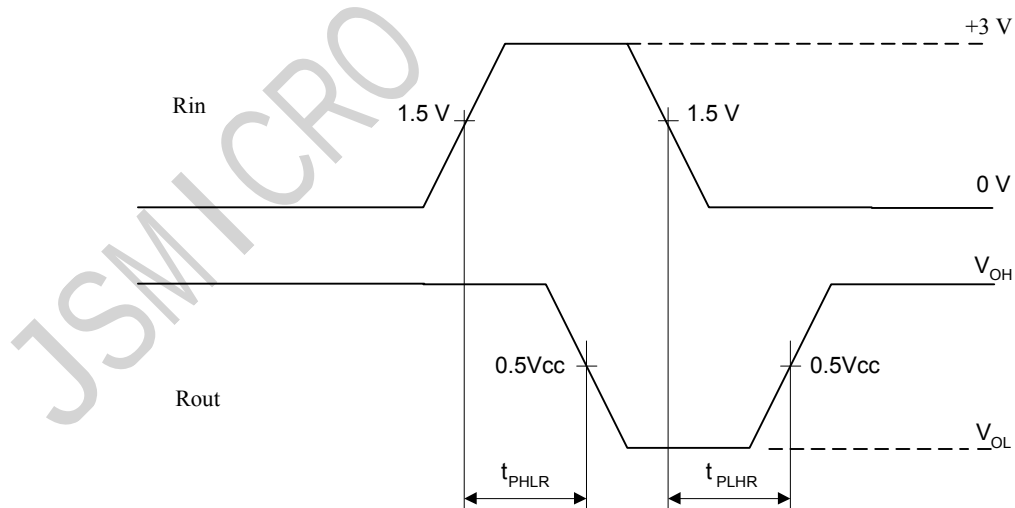


Figure 3

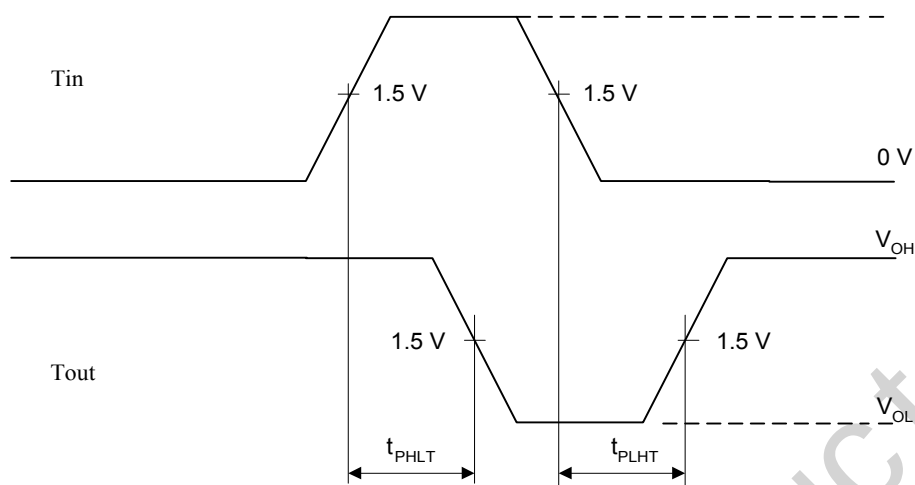


Figure 4

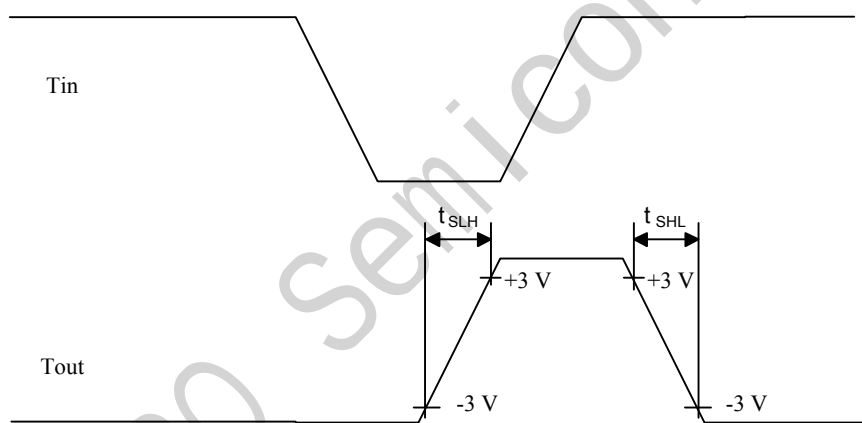


Figure 5

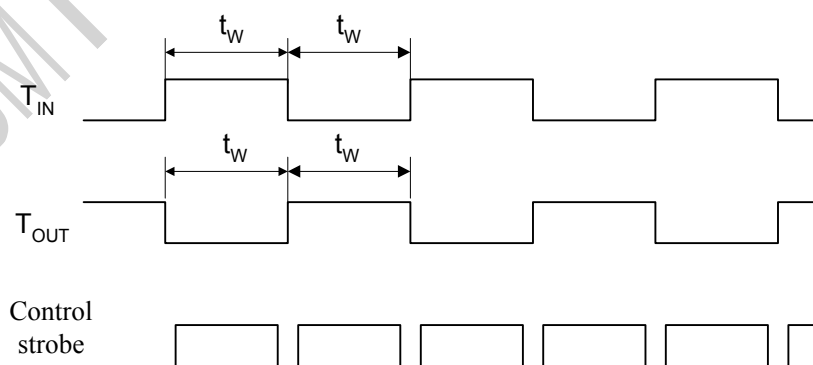
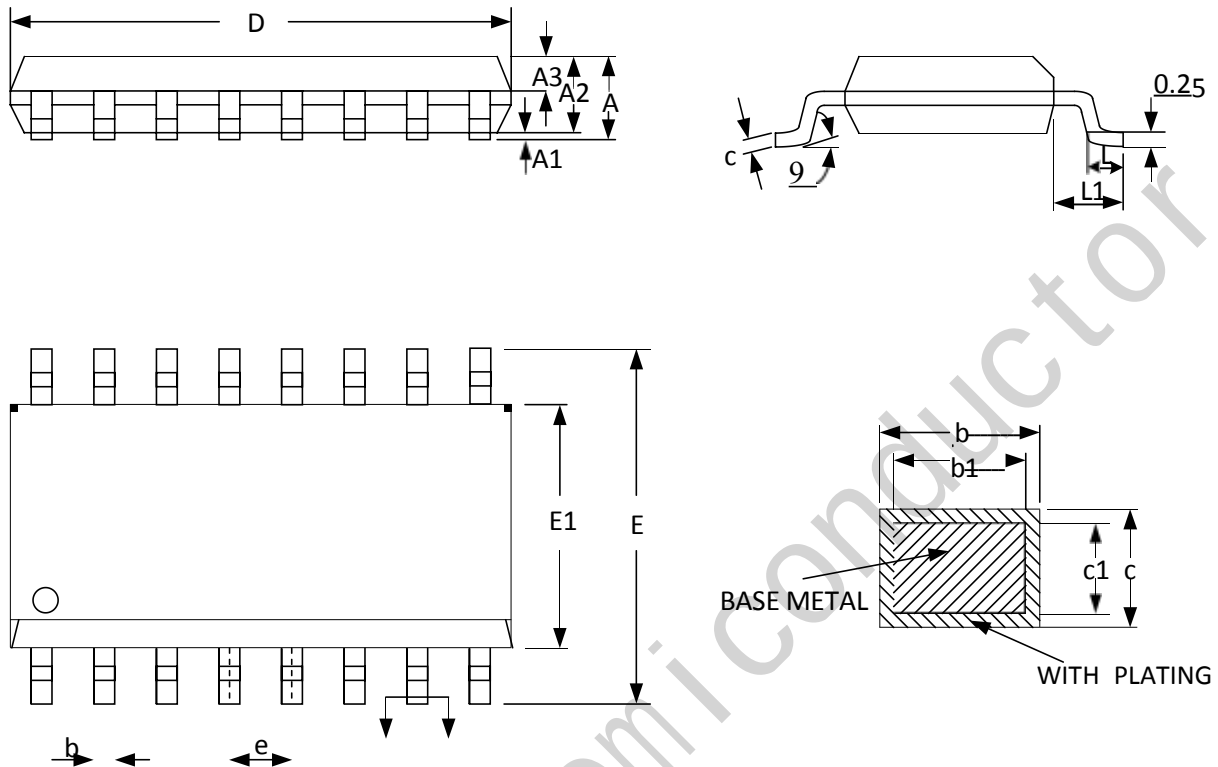


Figure 6

封装外形尺寸图

SOP16:



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	-	-	1.77
A1	0.08	0.18	0.28
A2	1.20	1.40	1.60
A3	0.55	0.65	0.75
b	0.39	-	0.48
b1	0.38	0.41	0.43
c	0.21	-	0.26
c1	0.19	0.20	0.21
D	9.70	9.90	10.10
E	5.80	6.00	6.20
E1	3.70	3.90	4.10
e	1.27BSC		
L	0.5	0.65	0.80
L1	1.05BSC		
9	0°	-	8°